

20A 400V Fast recovery diode

1 **Description**

20A, 400V Ultrafast Diodes They have a low forward voltage drop and are of planar, silicon nitride passivated, ion-implanted, epitaxial construction. These devices are intended for use as energy steering/clamping diodes and rectifiers in a variety of switching power supplies and other power switching applications. Their low stored charge and ultrafast recovery with soft recovery characteristics minimizes ringing and electrical noise in many power switching circuits, thus reducing power loss in the switching transistor TO-220F provides insulation voltage rated at 2000V RMS from all three terminals to external heatsink.

Features 2

- Low power loss,
- high efficiency Low forward voltage,
- high current capability High surge capacity
- Super fast recovery times
- high voltage

Applications 3

- Switching Power Supply
- **Power Switching Circuits**
- General Purpose

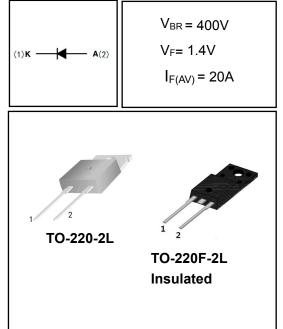
Electrical Characteristics Δ

4.

| PARAMETER | SYMBOL | VALUE | UNIT | |
|--------------------------------------|------------------|--------------------|---------|----|
| Peak Repetitive Reverse Voltage | V _{RRM} | 400 | V | |
| Working Peak Reverse Voltage | V _{RWM} | 400 | V | |
| DC Blocking Voltage | VR | 400 | V | |
| Average Rectified Forward Current | TO-220(Tc=135℃) | | 20 | Α |
| | TO-220F(Tc=100℃) | I _{F(AV)} | | |
| Repetitive Peak Surge Current | | IFRM | 30 | A |
| Nonrepetitive Peak Surge Current | t=8.3ms | I _{FSM} | 350 | A |
| Avalanche Energy | L=1mH | E _{AS} | 50 | mJ |
| Operating Junction Temperature Range | | Tj | -55~150 | °C |
| Storage Temperature Range | T _{stg} | -55~150 | °C | |

4.2 Thermal Characteristics

| PARAMETER | SYMBOL | VALUE | | UNIT |
|---|-------------------|--------|---------|--------------|
| FARAWETER | STNIDUL | TO-220 | TO-220F | UNIT |
| Thermal Resistance, Junction to Case-sink | R _{thJC} | 1.2 | 2.0 | °C /W |





4.3 Electrical Characteristics

| PARAMETER | SYMBOL | TEST CONDITION | MIN | TYP | MAX | UNIT |
|----------------------------------|------------------|--|-----|------|------|------|
| Maximum Instantaneous | VF | I _F = 20A | - | 1.21 | 1.4 | V |
| Forward Voltage | | I _F = 20A, T _C = 150℃ | - | - | 1.30 | V |
| | | I _F = 30A | - | 1.30 | 1.5 | V |
| Maximum Instantaneous | IR | V _R = 400V | - | - | 5 | uA |
| Reverse | | V _R = 400V, T _C = 150℃ | - | - | 2 | mA |
| Maximum Reverse Recovery Time | trr | V _R =50V,IF=1A -dI/dt=100A/us | - | 32 | 50 | ns |
| Maximum Reverse Recovery Time | trr | V _R =50V, IF=20A -dl/dt=100A/us | | 110 | | ns |
| Total capacitance | C _{tot} | V _R =0V f=1MHz | - | 470 | - | pF |
| DC Blocking Voltage | V _{BR} | I _R =100uA | 410 | 450 | - | V |

(Tc=25°C,unless otherwise noted)

DEFINITIONS

VF = Instantaneous forward voltage (pw = 300μ s, D = 2%).

IR = Instantaneous reverse current.

 $R\theta JC$ = Thermal resistance junction to case.

pw = pulse width.

D = duty cycle.

5 Typical characteristics diagrams

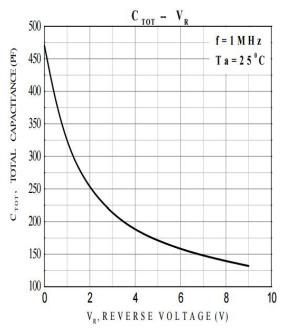


FIGURE 1. Total capacitance vs Voltage

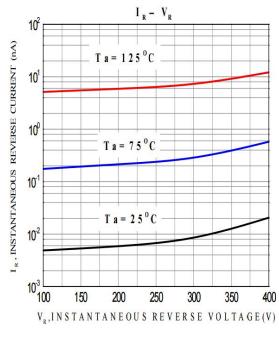


FIGURE 2. REVERSE CURRENT vs REVERSE VOLTAGE





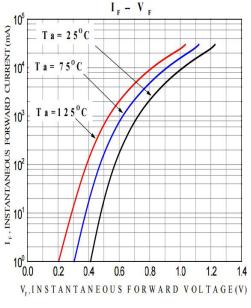


FIGURE 3. FORWARD CURRENT vs FORWARD VOLTAGE

6 Typical Test Circuit and Waveform

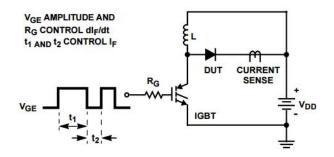


FIGURE 5. trr TEST CIRCUIT



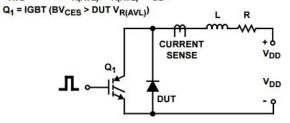


FIGURE 7. AVALANCHE ENERGY TEST CIRCUIT FIGURE

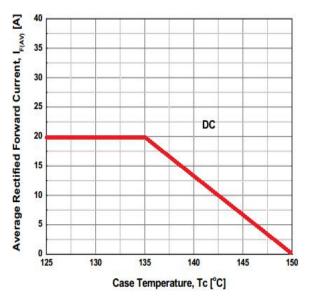


FIGURE 4. CURRENT DERATING CURVE

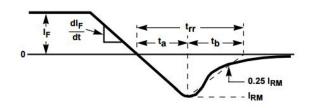


FIGURE 6. trr WAVEFORMS AND DEFINITIONS

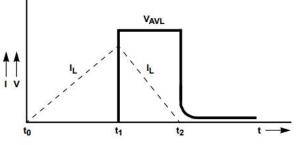
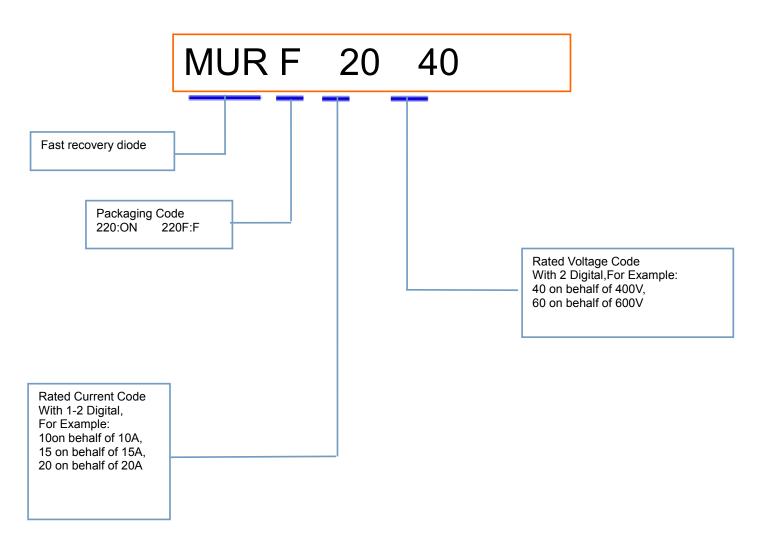


FIGURE8. AVALANCHE CURRENT AND VOLTAGE WAVEFORMS



7 Product Names Rules



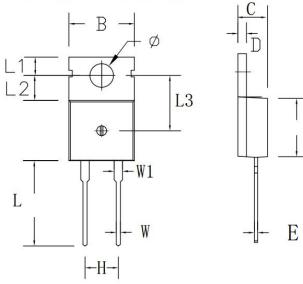
8 Product Specifications and Packaging Models

| Product Model | Package Type | Mark Name | RoHS | Package | Quantity |
|---------------|--------------|-----------|---------|---------|----------|
| MURF2040 | TO-220F-2L | MURF2040 | Pb-free | Tube | 1000/box |
| MUR2040 | TO-220-2L | MUR2040 | Pb-free | Tube | 1000/box |





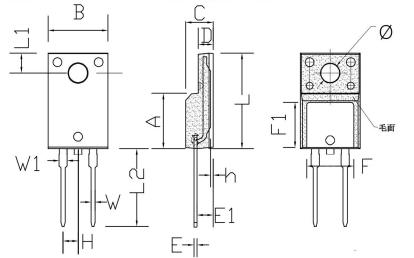
TO-220**C-2L** PACKAGE OUTLINE DIMENSIONS



Α

| C 1 1 | Dimensions | In Millimeters | Dimensions | In Inches |
|--------|------------|----------------|------------|-----------|
| Symbol | min. | max. | min. | max. |
| A | 9.15 | 9.25 | 0.361 | 0.364 |
| В | 9.95 | 10.05 | 0.392 | 0.396 |
| С | 4.45 | 4.55 | 0.175 | 0.179 |
| D | 1.28 | 1.32 | 0.050 | 0.052 |
| E | 0.48 | 0.52 | 0.019 | 0.020 |
| Н | 5.07 | 5.09 | 0.200 | 0.201 |
| W | 0.80 | 0.82 | 0.0315 | 0.0323 |
| W1 | 1.26 | 1.28 | 0.0496 | 0.0504 |
| L | 13.09 | 13.13 | 0.516 | 0.517 |
| L1 | 2.79 | 2.81 | 0.110 | 0.111 |
| L2 | 3.79 | 3.81 | 0.149 | 0.150 |
| L3 | 8.42 | 8.44 | 0.332 | 0.333 |
| Φ | 3.50 | 3.90 | 0.138 | 0.154 |
| | - | | | |

TO-220F-2 PACKAGE OUTLINE DIMENSIONS



| Currente el | DimensionsIn | Millimeters | Dimension | sln Inches |
|-------------|--------------|-------------|-----------|------------|
| Symbol | min. | max. | min. | max. |
| A | 8.80 | 9.30 | 0.346 | 0.366 |
| В | 10.00 | 10.50 | 0.394 | 0.413 |
| С | 4.30 | 4.90 | 0.169 | 0.193 |
| D | 2.30 | 2.70 | 0.091 | 0.106 |
| Ĺ | 15.55 | 16.15 | 0.612 | 0.636 |
| h | 0.40 | 0.60 | 0.016 | 0.024 |
| L1 | 3.15 | 3.55 | 0.124 | 0.140 |
| L2 | 12.65 | 13.35 | 0.498 | 0.526 |
| W | 0.70 | 0.90 | 0.028 | 0.035 |
| W1 | 1.15 | 1.55 | 0.045 | 0.061 |
| Н | 2.54 TYP | | 0.100 TYP | |
| E | 0.48 | 0.53 | 0.019 | 0.021 |
| φ | 2.90 | 3.40 | 0.114 | 0.134 |
| E1 | 2.40 | 2.90 | 0.094 | 0.114 |
| F | 7.75 | 8.25 | 0.305 | 0.325 |
| F1 | 7.35 | 7.85 | 0.289 | 0.309 |





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- It is the responsibility of the purchaser for any failure or failure of any semiconductor product under certain conditions. It is the responsibility of the purchaser to comply with safety standards and to take safety measures in the system design and machine manufacturing of WXDH products in order to avoid potential risk of failure. Injury or property damage.
- Product promotion is endless, our company will be dedicated to provide customers with better products.

11 Appendix

Revision history:

| Date | REV. | Description | Page |
|------------|------|-------------|------|
| 2017.09.13 | 1.0 | Original | |